

FORM PTO-1449 (SUBSTITUTE)

Attorney Docket No.:  
GR 96 P 8091 P

Applic. No.  
09/283,907

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE

Applicant

Michael Kelly et al.

Filing Date  
April 1, 1999

Group Art Unit  
2823

INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))



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TC 2000 MAIL ROOM

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>MS</i>	A	4,846,931	07/11/89	Gmitter et al.			
	B	5,465,009	11/02/95	Drabik et al.			
	C						
	D						
	E						
	F						
	G						
	H						
	I						

FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J						
	K						
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	O	
	P	

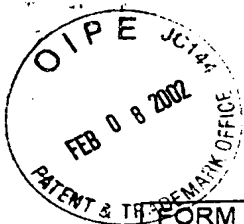
EXAMINER

*William D. [Signature]*

DATE CONSIDERED

*April 16, 2002*

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



SHEET 1 OF 4

FORM PTO-1449 (SUBSTITUTE)

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PATENT AND TRADEMARK OFFICEINFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
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09/28,907

Applicant  
MICHAEL KELLY ET AL.Filing Date  
APRIL 1, 1999

Group Art Unit

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A	4,448,636	05/84	Baber	—	—	
	B	4,883,561	11/89	Gmitter et al.	—	—	
	C						
	D						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES	NO
	J	3508469A1	09/86	Germany	—	—		X
	K	0718885A2	06/96	Europe	—	—		X
	L							
	M							
	N							

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

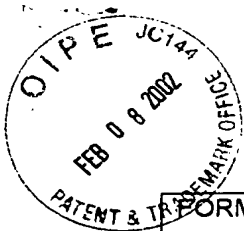
		"Optical patterning of GaN films", M.K. Kelly et al., Appl. Phys. Lett. 69 (12), September 16, 1996, pp. 1749-1751
		"Extreme selectivity in the lift-off of epitaxial GaAs films", Eli Yablonovitch et al., Appl. Phys. Lett. 51 (26), December 28, 1987, pp. 2222-2224

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SHEET 2 OF 4

FORM PTO-1449 (SUBSTITUTE)	Attorney Docket No.: GR 96 P 8091	Appl. No. <b>09/283,907</b>
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	Applicant MICHAEL KELLY ET AL.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))	Filing Date APRIL 1, 1999	Group Art Unit

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A						
	B						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J						
	K						
	L						
	M						
	N						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

		"On the Thermal Decomposition of GaN in Vacuum", R. Groh et al., pp. 353-357
		"Few Characteristics of Epitaxial GaN-Etching and Thermal Decomposition", Yasua Morimoto, J. Electrochem. Soc.: Solid-State Science and Technology, October 1974, pp. 1383-1384

EXAMINER

DATE CONSIDERED

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